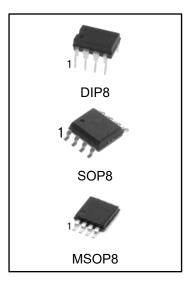


# **CMOS** general purpose timer

### Features

- Exact equivalent in most cases for SE/NE555.
- Low Supply Current.
- High speed operation 500 kHz guaranteed.
- Wide operation supply voltage range 2 to 18 volts.
- Timing from microseconds through hours.
- Operates in both astable and monostable modes.
- Adjustable duty cycle.
- High output source/sink driver can drive TTL/CMOS

## **Ordering Information**



DEVICE	Package Type	MARKING	Packing	Packing Qty
TLC555N	DIP8	TLC555	TUBE	2000/box
TLC555M/TR	SOP8	TLC555	REEL	2500/reel
TLC555MM/TR	MSOP8	TLC555	REEL	3000/reel

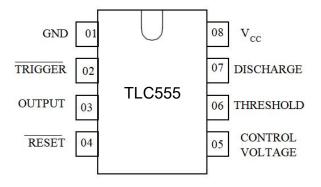


### **General Description**

The TLC555 is CMOS RC timers providing significantly improved performance over the standard SE/NE555 and 355 timers, while at the same time being direct replacements for those devices in most applications. Improved parameters include low supply current, wide operating supply voltage range, low THRESHOLD, TRIGGER and RESET currents, no crowbarring of the supply current during output transitions, higher frequency performance and no requirement to decouple CONTROL VOLTAGE for stable operation.

Specifically, the TLC555 is stable controller capable of producing accurate time delays of frequencies.

### **PIN ASSIGNMENT**



#### TRUTH TABLE

THRESHOLD	TRIGGER	RESET	OUTPUT	DISCHARGE
X	X L		L	ON
> 2/3 V <sub>CC</sub>	> 1/3 V <sub>CC</sub>	Н	L	ON
< 2/3 V <sub>CC</sub>	> 1/3 V <sub>CC</sub>	Н	STABLE	STABLE
Х	< 1/3 V <sub>CC</sub>	Н	Н	OFF



## Maximum Ratings And Recommended Operating Conditions

		Recomn operatingc		Maximum ratings		
Parameter, unit	Symbol	Val	ue	Val	ue	
		min	max	min	max	
Supply Voltage, V	VCC	2.0	18.0	0	18.0	
Output Current, mA	lo	-	20	-	100	
Input Voltage, V	VTH, VTRIG, VRST	-	-	-0.3	V <sub>CC</sub> +0.3	
Power Dissipation, mW	PD	-	-	-	200	
Operating Temperature,°C	TOPR	0	70	0	70	
Storage Temperature,°C	TSTG	-	-	-65	150	
Lead Temperature, 1 mm from Case for 10 Seconds,°C	TSOLDER	-	-		260	



## DC ELECTRICAL CHARACTERISTICS (Voltages Referenced to GND)

	0 1 1	Test Condit	ions	Val	Tempe-		
Parameter, units	Symbol	IOL, IOH	VCC, B	min	max	rature, °C	
	VTH		5.0	0.65 Vcc	0.70 Vcc	$25\pm10$	
Threshold Voltage, V	۷IП		5.0	0.60 V <sub>CC</sub>	0.80 V <sub>CC</sub>	-20, 70	
Trigger voltage, V	VTRIG		5.0	0.31 V <sub>CC</sub>	0.36 V <sub>CC</sub>	$25\pm10$	
	VING		5.0	0.28 V <sub>CC</sub>	0.40 V <sub>CC</sub>	-20, 70	
			2.0	0.4	1.0	25±10	
Reset voltage, V	VRST		18.0	0.4	1.0	20 - 10	
			2.0	0.2	1.5	-20, 70	
			18.0	0.2	1.0	-20, 70	
Control Voltage Lead, V	VCV			0.65 V <sub>CC</sub>	0.69 V <sub>CC</sub>	25 10	
Control voltage Lead, v	v0v			0.60 V <sub>cc</sub>	0.80 V <sub>CC</sub>	-20, 70	
	VOL	I <sub>OL</sub> = 3.2 mA	5.0		0.4	25±10	
Output voltage Low, V		I <sub>OL</sub> = 20 mA	15.0		1.0	20 - 10	
		I <sub>OL</sub> = 3.2 mA	5.0		0.6	-20, 70	
		I <sub>OL</sub> = 20 mA	15.0		1.5	-20, 70	
			5.0	4.0		25±10	
Output voltage High, V	Vон	I <sub>он</sub> = -0.8 mA	15.0	14.3		25 - 10	
Output voltage riigh, v	VOIT	10H0.0 IIIA	5.0	3.5		-20, 70	
			15.0	14.0		-20, 70	
			2.0		200	25±10	
Supply Current, µA	ICC		18.0		300	20 <u>1</u> 10	
	100		2.0		400	-20, 70	
			18.0		600	-20, 70	



## AC ELECTRICAL CHARACTERISTICS

		Test Conditions		Va	Tempe-	
Parameter, unit	Symbol	$R_L, C_L$	VCC, V	Min	Max	rature, °C
Rise (Fall) Time of	tTHL,	R <sub>L</sub> = 10 MΩ, C <sub>L</sub> = 10 pF	5.0	35	75	25±10
Output,ns	ttlh	· · ·		70	150	-20, 70
Guaranteed Max	I IMAX   Astable		2.0-	500		25±10
Osc Freq,kHz			18.0	200		-20, 70
Initial accuracy, %				5		
Drift with Tomporature			5.0		0.02	
Drift with Temperature, %/°C	αf	R∟ = 1 - 100 kΩ	10.0		0.03	-20, 70
70/ C		C∟= 0.1 µF	15.0		0.06	
Drift with Supply Voltage,	٨f		5.0		3	$25\pm10$
%/B	Δf		5.0		6	-20, 70

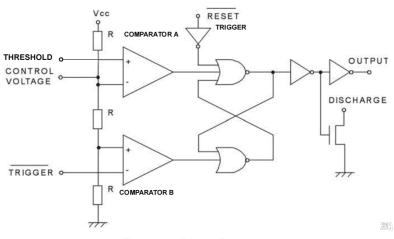


Figura 1. Block Diagram

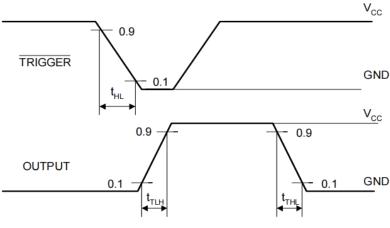
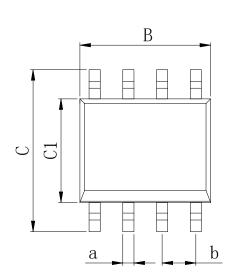


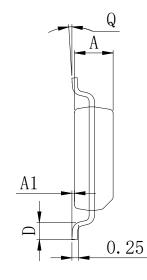
Figura 2. Switcing Waveforms



## **Physical Dimensions**

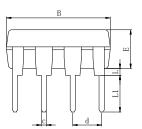
SOP8



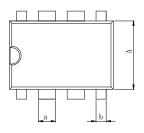


Dimensions In Millimeters(SOP8)									
Symbol:	A	A1	В	С	C1	D	Q	а	b
Min:	1.35	0.05	4.90	5.80	3.80	0.40	0°	0.35	1.27 BSC
Max:	1.55	0.20	5.10	6.20	4.00	0.80	8°	0.45	1.27 030

#### DIP8





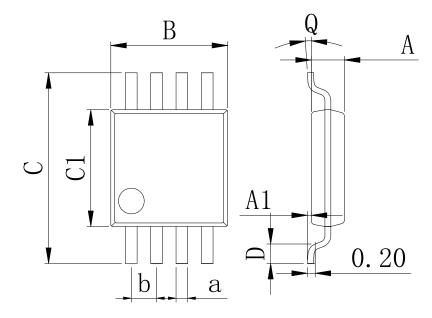


Dimensions In Millimeters(DIP8)											
Symbol:	A	В	D	D1	Е	L	L1	а	b	с	d
Min:	6.10	9.00	8.40	7.42	3.10	0.50	3.00	1.50	0.85	0.40	2.54.000
Max:	6.68	9.50	9.00	7.82	3.55	0.70	3.60	1.55	0.90	0.50	2.54 BSC



## **Physical Dimensions**

MSOP8



Dimensions In Millimeters(MSOP8)									
Symbol:	A	A1	В	С	C1	D	Q	а	b
Min:	0.80	0.05	2.90	4.75	2.90	0.35	0°	0.25	0.65 BSC
Max:	0.90	0.20	3.10	5.05	3.10	0.75	8°	0.35	0.05 650



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